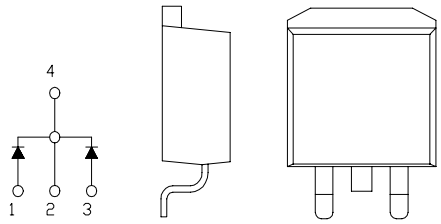
Nihon Inter Electronics Corporation

FRD Type : C16T20F

OUTLINE DRAWING

FEATURES

* **SQUARE-PAK** TO263AB Case (SMD)
  Packaged in 24mm Tape and Reel
* Dual Diodes – Cathode Common
* Ultra – Fast Recovery
* Low Forward Voltage Drop
* High Surge Capability
* 200 Volts thru 600 Volts Types Available



Maximum Ratings

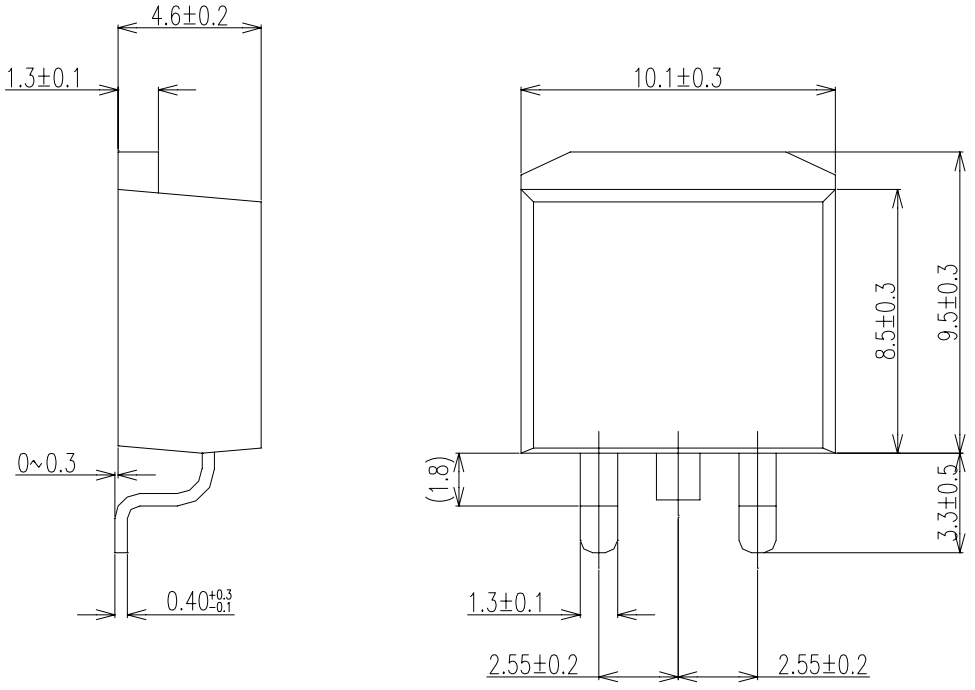
Approx Net Weight:1.4g

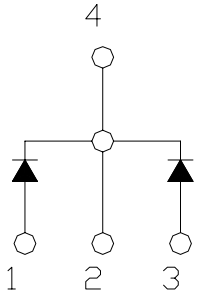
Rating	Symbol	C16T20F			Unit
Repetitive Peak Reverse Voltage	V_{RRM}	200			V
Non-repetitive Peak Reverse Voltage	V_{RSM}	220			V
Average Rectified Output Current	I_O	16	Tc=113℃	50 Hz,Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	18			A
Surge Forward Current	I_{FSM}	120	50 Hz Full Sine Wave,1cycle Non-repetitive		A
Operating JunctionTemperature Range	Tjw	- 40 to + 150			℃
Storage Temperature Range	Tstg	- 40 to + 150			℃

Electrical • Thermal Characteristics

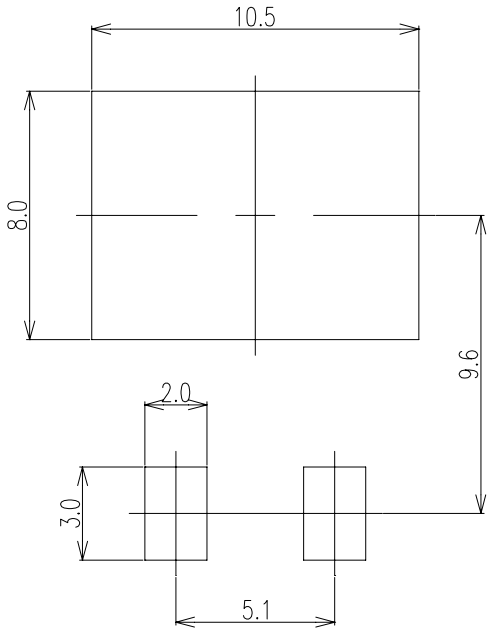
Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	Tj=25℃,V_{RM}=V_{RRM} per Arm	-	-	25	μA
Peak Forward Voltage	V_{FM}	Tj=25℃, I_{FM}=8A per Arm	-	-	0.98	V
Reverse Recovery Time	trr	I_{FM}= 8 A, -di/dt= 50 A/μs, Ta= 25℃	-	-	35	ns
Thermal Resistance	Rth(j-c)	Junction to Case	-	-	2	℃/W

C_T_ OUTLINE DRAWING (Dimensions in mm)





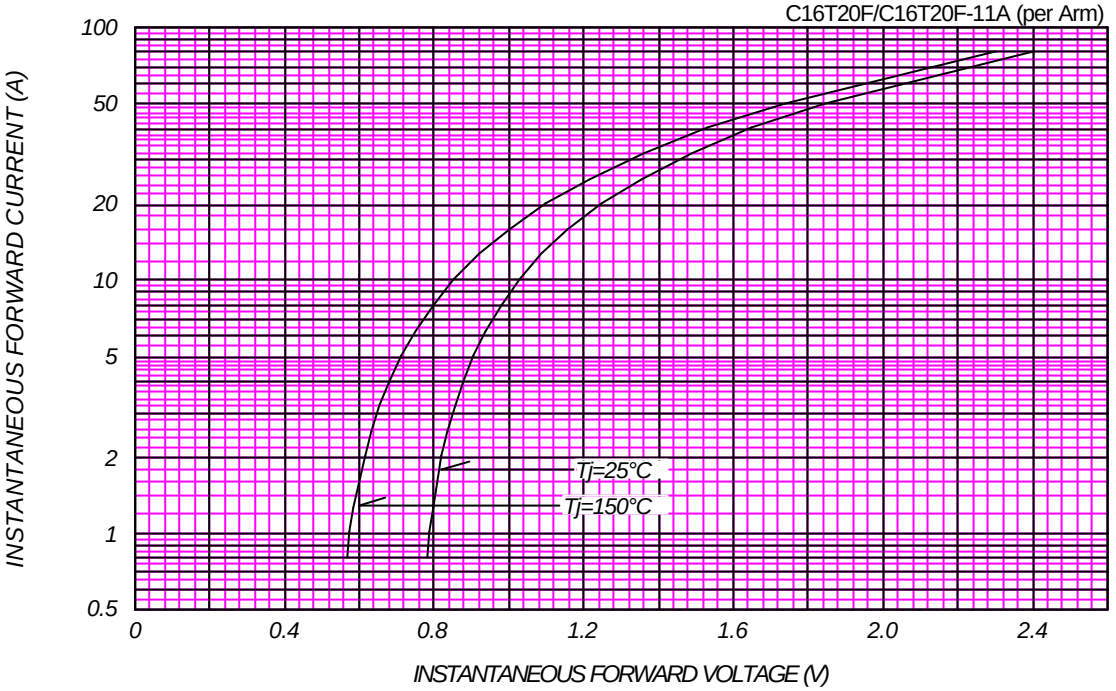
SOLDERING PAD

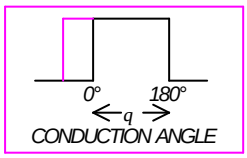


FORWARD CURRENT VS. VOLTAGE

10ms Sine Wave Single Pulse

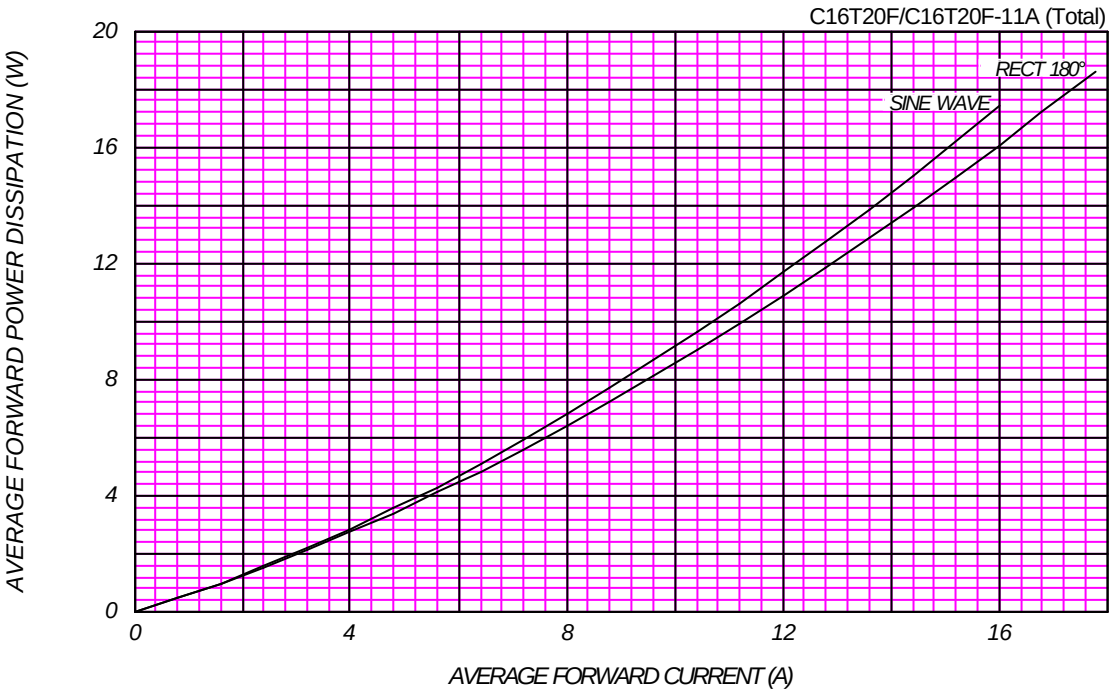
C16T20F/C16T20F-11A (per Arm)

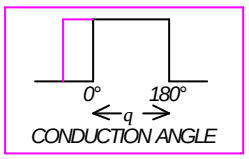




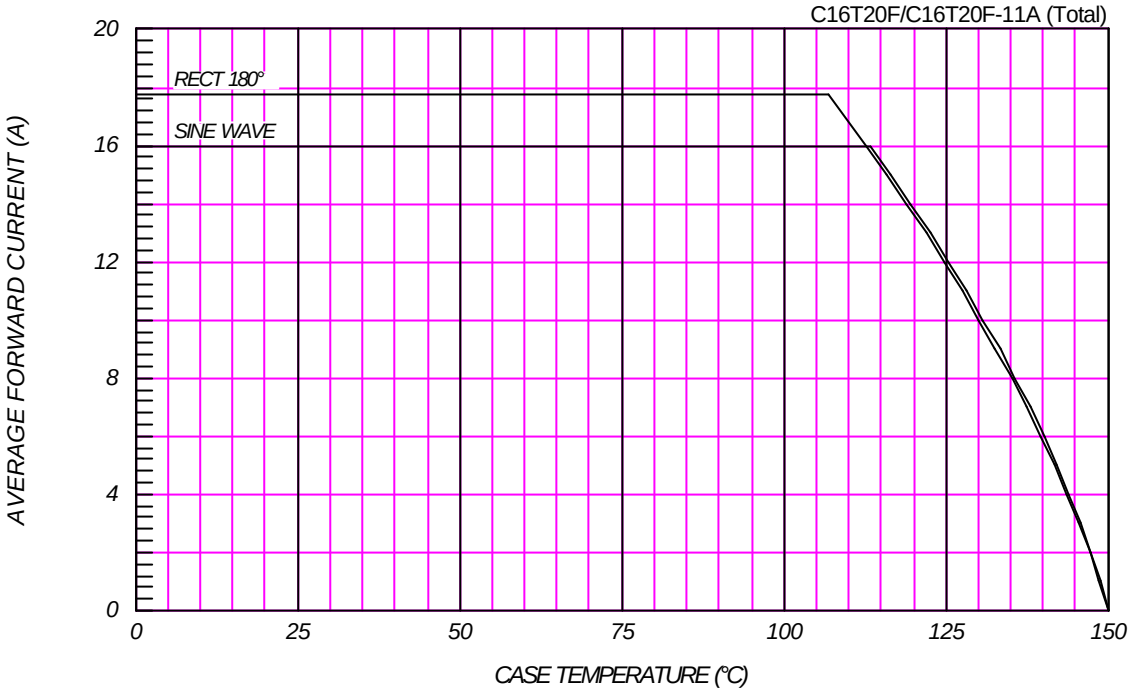
AVERAGE FORWARD POWER DISSIPATION

C16T20F/C16T20F-11A (Total)





AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE



SURGE CURRENT RATINGS

f=50Hz,Sine Wave,Non-Repetitive,No Load

